

FDW254PZ

P-Channel 1.8V Specified PowerTrench[®] MOSFET

General Description

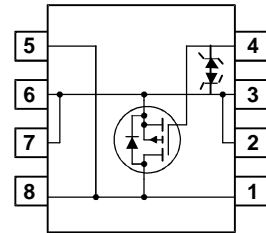
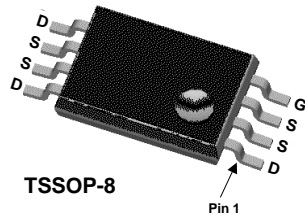
This P-Channel 1.8V specified MOSFET is a rugged gate version of Fairchild Semiconductor's advanced PowerTrench process. It has been optimized for power management applications with a wide range of gate drive voltage (1.8V – 8V).

Applications

- Load switch
- Motor drive
- DC/DC conversion
- Power management

Features

- -9.2 A, -20 V. $R_{DS(ON)} = 12\text{ m}\Omega @ V_{GS} = -4.5\text{ V}$
 $R_{DS(ON)} = 15\text{ m}\Omega @ V_{GS} = -2.5\text{ V}$
 $R_{DS(ON)} = 21.5\text{ m}\Omega @ V_{GS} = -1.8\text{ V}$
- Rds ratings for use with 1.8 V logic
- ESD protection diode
- Low gate charge
- High performance trench technology for extremely low $R_{DS(ON)}$
- Low profile TSSOP-8 package



Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{DSS}	Drain-Source Voltage	-20	V
V _{GSS}	Gate-Source Voltage	±8	V
I _D	Drain Current – Continuous (Note 1) – Pulsed	-9.2	A
		-50	
P _D	Power Dissipation (Note 1a) (Note 1b)	1.4	W
		1	
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Thermal Characteristics

R _{θJA}	Thermal Resistance, Junction-to-Ambient (Note 1a) (Note 1b)	96	°C/W
		208	

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
254PZ	FDW254PZ	13"	12mm	3000 units

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
Off Characteristics						
BV_{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = -250\ \mu\text{A}$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$, Referenced to 25°C		-11		mV/ $^\circ\text{C}$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -16\text{ V}, V_{GS} = 0\text{ V}$			-1	μA
I_{GSS}	Gate–Body Leakage	$V_{GS} = \pm 8\text{ V}, V_{DS} = 0\text{ V}$			± 10	μA
On Characteristics (Note 2)						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250\ \mu\text{A}$	-0.4	-0.6	-1.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate Threshold Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$, Referenced to 25°C		2		mV/ $^\circ\text{C}$
$R_{DS(on)}$	Static Drain–Source On–Resistance	$V_{GS} = -4.5\text{ V}, I_D = -9.2\text{ A}$ $V_{GS} = -2.5\text{ V}, I_D = -7.9\text{ A}$ $V_{GS} = -1.8\text{ V}, I_D = -6.5\text{ A}$ $V_{GS} = -4.5\text{ V}, I_D = -9.2\text{ A}, T_J = 125^\circ\text{C}$		9 11 14 12	12 15 21.5 18	m Ω
$I_{D(on)}$	On–State Drain Current	$V_{GS} = -4.5\text{ V}, V_{DS} = -5\text{ V}$	-50			A
g_{FS}	Forward Transconductance	$V_{DS} = -5\text{ V}, I_D = -9.2\text{ A}$		54		S
Dynamic Characteristics						
C_{iss}	Input Capacitance	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V},$ $f = 1.0\text{ MHz}$		5880		pF
C_{oss}	Output Capacitance			990		pF
C_{rss}	Reverse Transfer Capacitance			560		pF
R_G	Gate Resistance	$V_{GS} = 15\text{ mV}, f = 1.0\text{ MHz}$		4.9		Ω
Switching Characteristics (Note 2)						
$t_{d(on)}$	Turn–On Delay Time	$V_{DD} = -10\text{ V}, I_D = -1\text{ A},$ $V_{GS} = -4.5\text{ V}, R_{GEN} = 6\ \Omega$		15	27	ns
t_r	Turn–On Rise Time			15	27	ns
$t_{d(off)}$	Turn–Off Delay Time			210	336	ns
t_f	Turn–Off Fall Time			100	160	ns
Q_g	Total Gate Charge	$V_{DS} = -10\text{ V}, I_D = -9.2\text{ A},$ $V_{GS} = -4.5\text{ V}$		60	96	nC
Q_{gs}	Gate–Source Charge			7		nC
Q_{gd}	Gate–Drain Charge			13		nC
Drain–Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain–Source Diode Forward Current				-1.2	A
V_{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = -1.2\text{ A}$ (Note 2)		-0.5	-1.2	V
t_{rr}	Reverse Recovery Time	$I_F = -9.2\text{ A},$ $d_I/d_t = 100\text{ A}/\mu\text{s}$		35		ns
Q_{rr}	Reverse Recovery Charge			21		nC

Notes:

- $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.
 - $R_{\theta JA}$ is $96^\circ\text{C}/\text{W}$ (steady state) when mounted on a 1 inch² copper pad on FR-4.
 - $R_{\theta JA}$ is $208^\circ\text{C}/\text{W}$ (steady state) when mounted on a minimum copper pad on FR-4.

- Pulse Test: Pulse Width < μs , Duty cycle < 2.0%.

Typical Characteristics

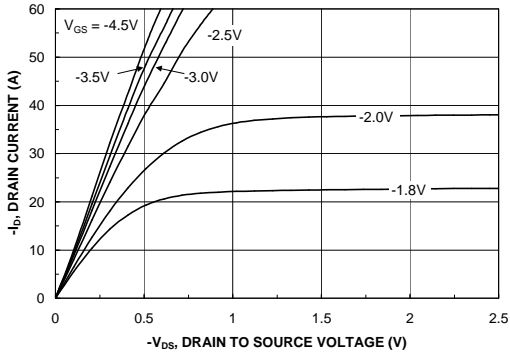


Figure 1. On-Region Characteristics.

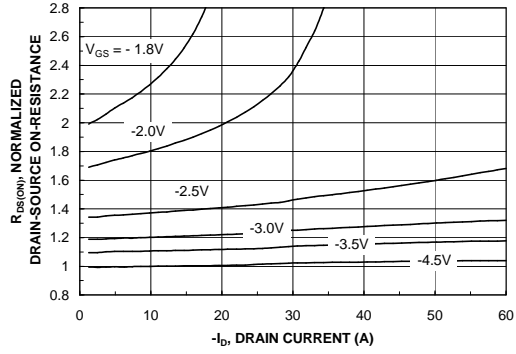


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage.

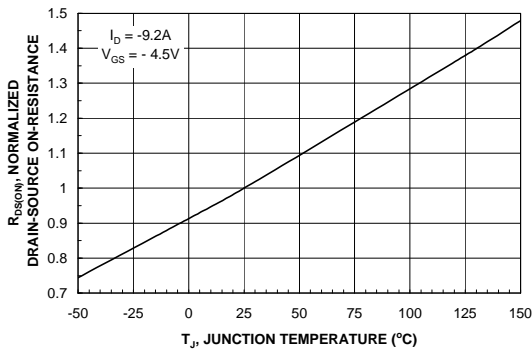


Figure 3. On-Resistance Variation with Temperature.

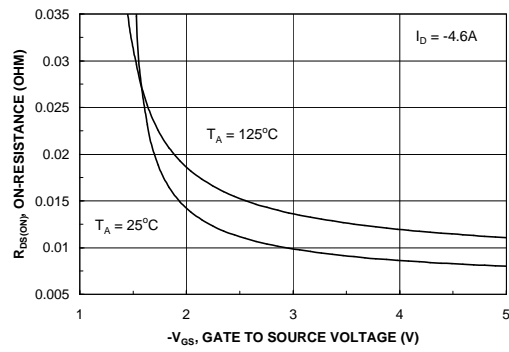


Figure 4. On-Resistance Variation with Gate-to-Source Voltage.

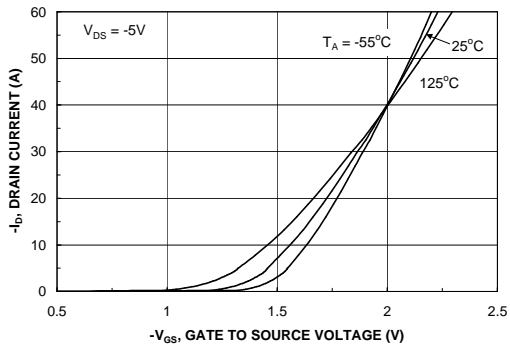


Figure 5. Transfer Characteristics.

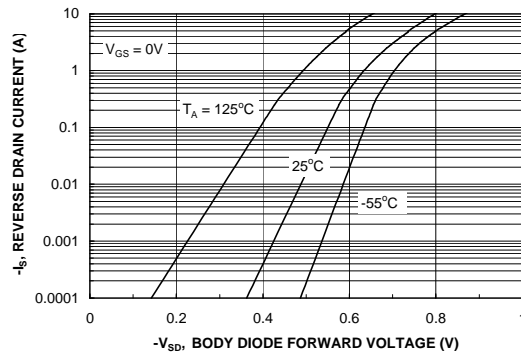


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature.

Typical Characteristics

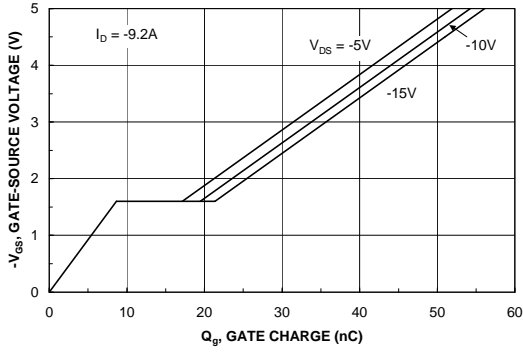


Figure 7. Gate Charge Characteristics.

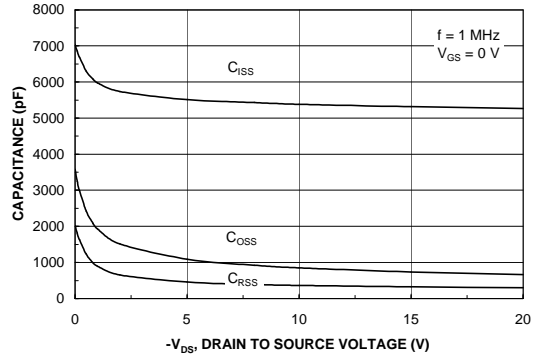


Figure 8. Capacitance Characteristics.

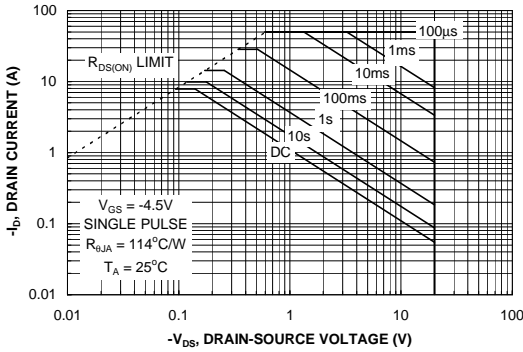


Figure 9. Maximum Safe Operating Area.

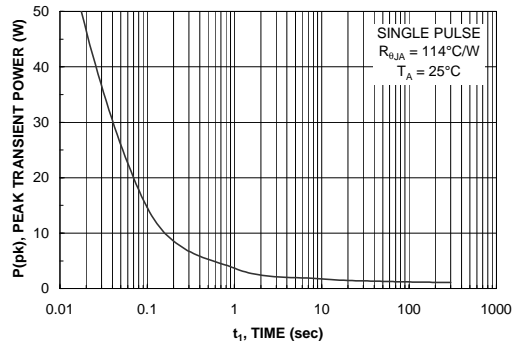


Figure 10. Single Pulse Maximum Power Dissipation.

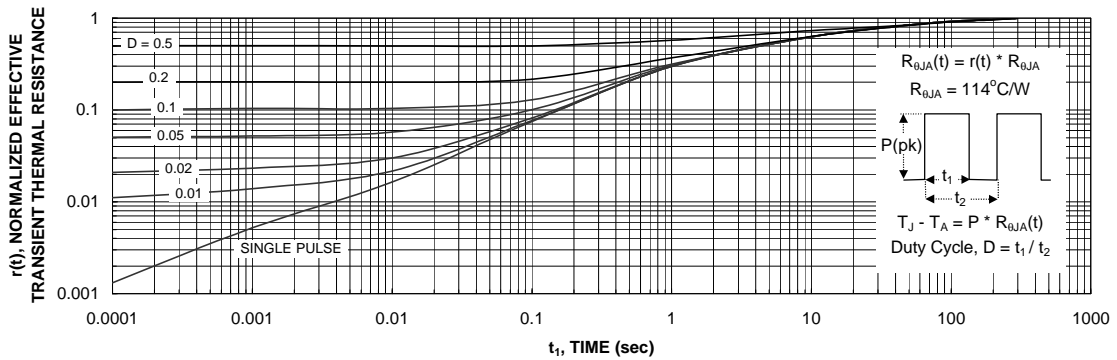


Figure 11. Transient Thermal Response Curve.

Thermal characterization performed using the conditions described in Note 1b. Transient thermal response will change depending on the circuit board design.

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